

TOSHIBA CCD LINEAR IMAGE SENSOR CCD (Charge Coupled Device)

TCD1705D

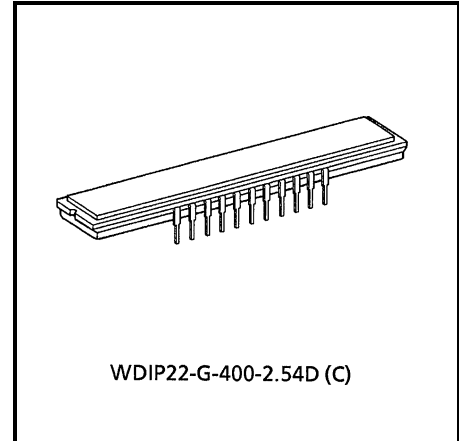
The TCD1705D is a high sensitive and low dark current 7450 elements CCD image sensor.

The sensor is designed for facsimile, imagescanner and OCR.

The device contains a row of 7450 elements photodiodes which provide a 24 lines / mm (600DPI) across a A3 size paper. The device is operated by 5 V (pulse), and 12 V power supply.

FEATURES

- Number of Image Sensing Elements : 7450 elements
- Image Sensing Element Size : 4.7 μm by 4.7 μm on 4.7 μm centers
- Photo Sensing Region : High sensitive and low voltage dark signal pn photodiode
- Clock : 2 phase (5 V)
- Package : 22 pin Cerdip



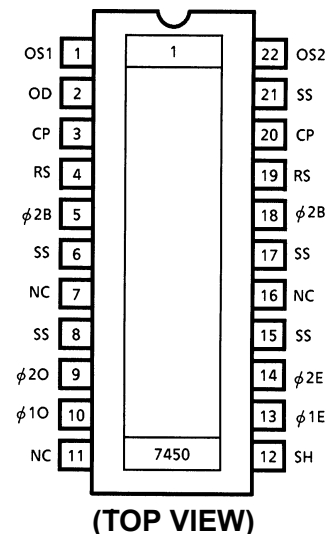
Weight : 5.2g (Typ.)

MAXIMUM RATINGS (Note 1)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	V_{ϕ}	-0.3~8	V
Shift Pulse Voltage	V_{SH}		
Reset Pulse Voltage	V_{RS}		
Clamp Pulse Voltage	V_{CP}		
Power Supply Voltage	V_{OD}	-0.3~15	
Operating Temperature	T_{opr}	0~60	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-25~85	$^{\circ}\text{C}$

Note 1: All voltage are with respect to SS terminals (Ground).

PIN CONNECTION



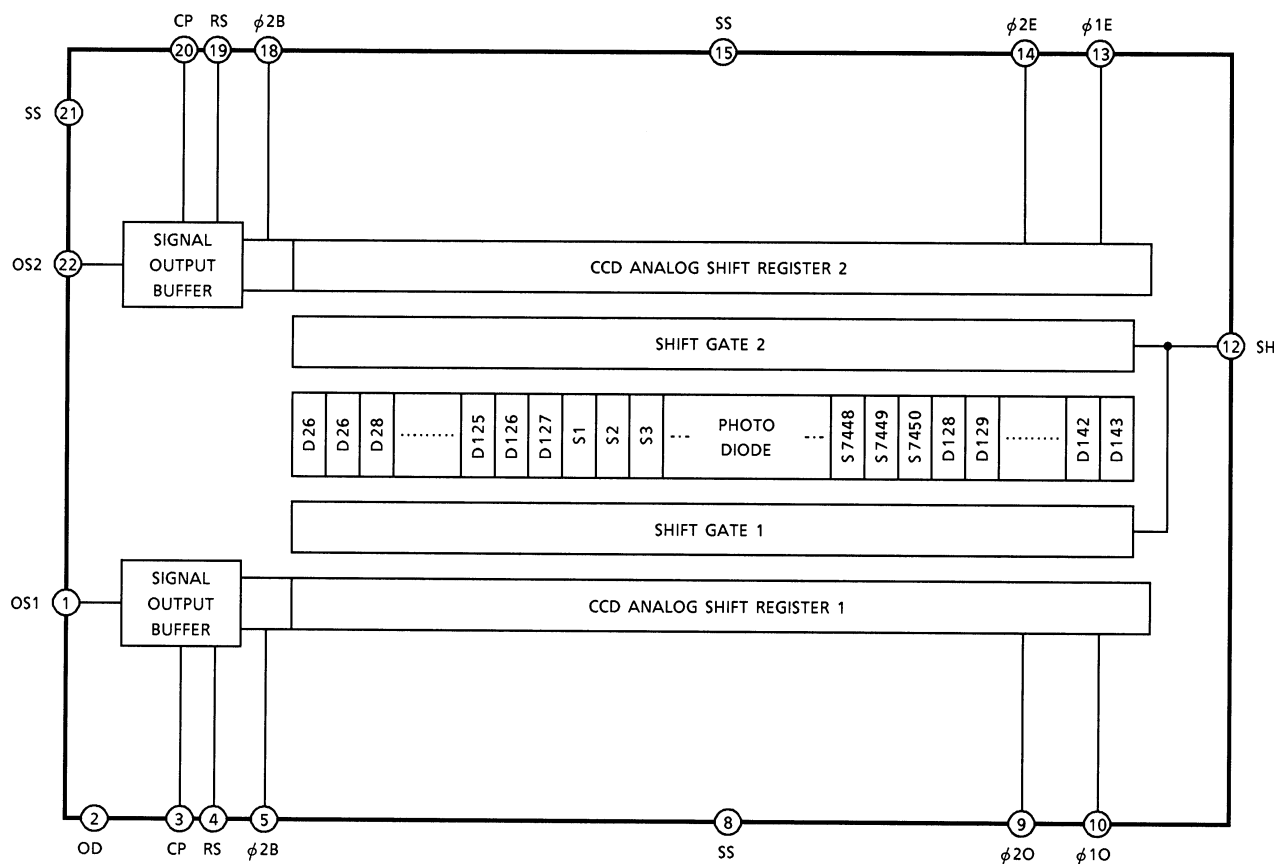
000707EBA2

• TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

• The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

CIRCUIT DIAGRAM



PIN NAMES

$\phi 1E$, O	Clock (Phase 1)
$\phi 2E$, O	Clock (Phase 2)
$\phi 2B$	Final Stage Clock (Phase 2)
SH	Shift Gate
RS	Reset Gate
CP	Clamp Gate
OS1	Signal Output 1
OS2	Signal Output 2
OD	Power
SS	Ground
NC	Non Connection

000707EBA2

- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V_{OD} = 12 V, V_φ = V_{SH} = V_{RS} = V_{CP} = 5 V (PULSE), f_φ = 1 MHz,
t_{INT} (INTEGRATION TIME) = 10 ms, LIGHT SOURCE = DAYLIGHT FLUORESCENT LAMP,
LOAD RESISTANCE = 100 kΩ)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Sensitivity	R	12	15	18	V / lx·s	
Photo Response Non Uniformity	PRNU	—	4	10	%	(Note 2)
	PRNU (3)	—	6	12	mV	(Note 8)
Saturation Output Voltage	V _{SAT}	1.0	1.3	—	V	(Note 3)
Saturation Exposure	SE	0.05	0.08	—	lx·s	(Note 4)
Dark Signal Voltage	V _{DRK}	—	1.0	3	mV	(Note 5)
Dark Signal Non Uniformity	DSNU	—	4.0	10	mV	(Note 5)
DC Power Dissipation	P _D	—	350	480	mW	
Total Transfer Efficiency	TTE	92	98	—	%	
Output Impedance	Z _o	—	0.2	1	kΩ	
Dynamic Range	DR	—	1300	—	—	(Note 6)
DC Signal Output Voltage	V _{OS1}	4.5	6.0	7.5	V	(Note 7)
	V _{OS2}	4.5	6.0	7.5		
DC Differential Error Voltage	V _{OS1} - V _{OS2}	—	—	300	mV	
Random Noise	NDσ	—	1.7	—	mV	(Note 9)

Note 2: Measured at 50% of SE (Typ.)

$$\text{Definition of PRNU : PRNU} = \frac{\Delta\bar{\chi}}{\bar{\chi}} \times 100(\%)$$

Where $\bar{\chi}$ is average of total signal outputs and $\Delta\bar{\chi}$ is maximum deviation from $\bar{\chi}$ under uniform illumination.
(Channel 1)

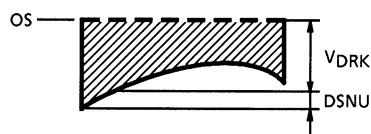
In the case of 3725 elements (Channel 2), the condition is the same as above too.

Note 3: V_{SAT} is defined as minimum saturation output voltage of all effective pixels.

$$\text{Note 4: Definition of SE : SE} = \frac{V_{SAT}}{R} (\text{lx} \cdot \text{s})$$

Note 5: V_{DRK} is defined as average dark signal voltage of all effective pixels.

$DSNU$ is defined as different voltage between V_{DRK} and V_{MDK} when V_{MDK} is maximum dark signal voltage.

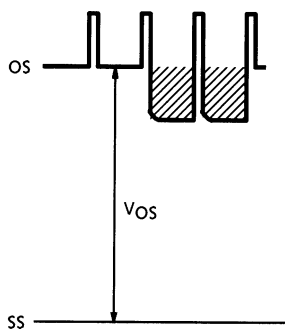


Note 6: Definition of DR : $DR = \frac{V_{SAT}}{V_{DRK}}$

V_{DRK} is proportional to t_{INT} (Integration Time).

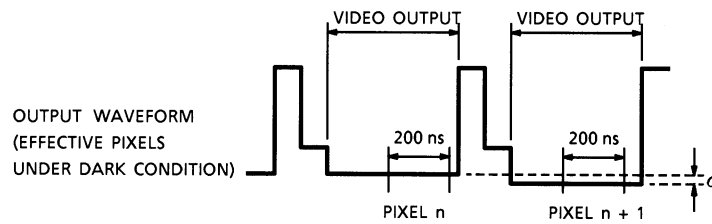
So the shorter t_{INT} condition makes wider DR values.

Note 7: DC signal output voltage and DC compensation output voltage are defined as follows:



Note 8: PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (Typ.)

Note 9: Random noise is defined as the standard deviation (sigma) of the output level difference between two adjacent effective pixels under no illumination (i.e. dark condition) calculated by the following procedure.



- 1) Two adjacent pixels (pixel n and n + 1) in one reading are fixed as measurement points.
- 2) Each of the output levels at video output periods averaged over 200 nanosecond period to get V_n and V_{n+1} .
- 3) V_{n+1} is subtracted from V_n to get ΔV .

$$\Delta V = V_n - V_{n+1}$$
- 4) The standard deviation of ΔV is calculated after procedure 2) and 3) are repeated 30 times (30 readings).

$$\overline{\Delta V} = \frac{1}{30} \sum_{i=1}^{30} |\Delta V_i| \quad \sigma = \sqrt{\frac{1}{30} \sum_{i=1}^{30} (|\Delta V_i| - \overline{\Delta V})^2}$$

- 5) Procedure 2), 3) and 4) are repeated 10 times to get 10 sigma values.

$$\overline{\sigma} = \frac{1}{10} \sum_{j=1}^{10} \sigma_j$$

- 6) $\overline{\sigma}$ value calculated using the above procedure is observed $\sqrt{2}$ times larger than that measured relative to the ground level. So we specify the random noise as follows.

$$\text{Random noise} = \frac{1}{\sqrt{2}} \overline{\sigma}$$

OPERATING CONDITION

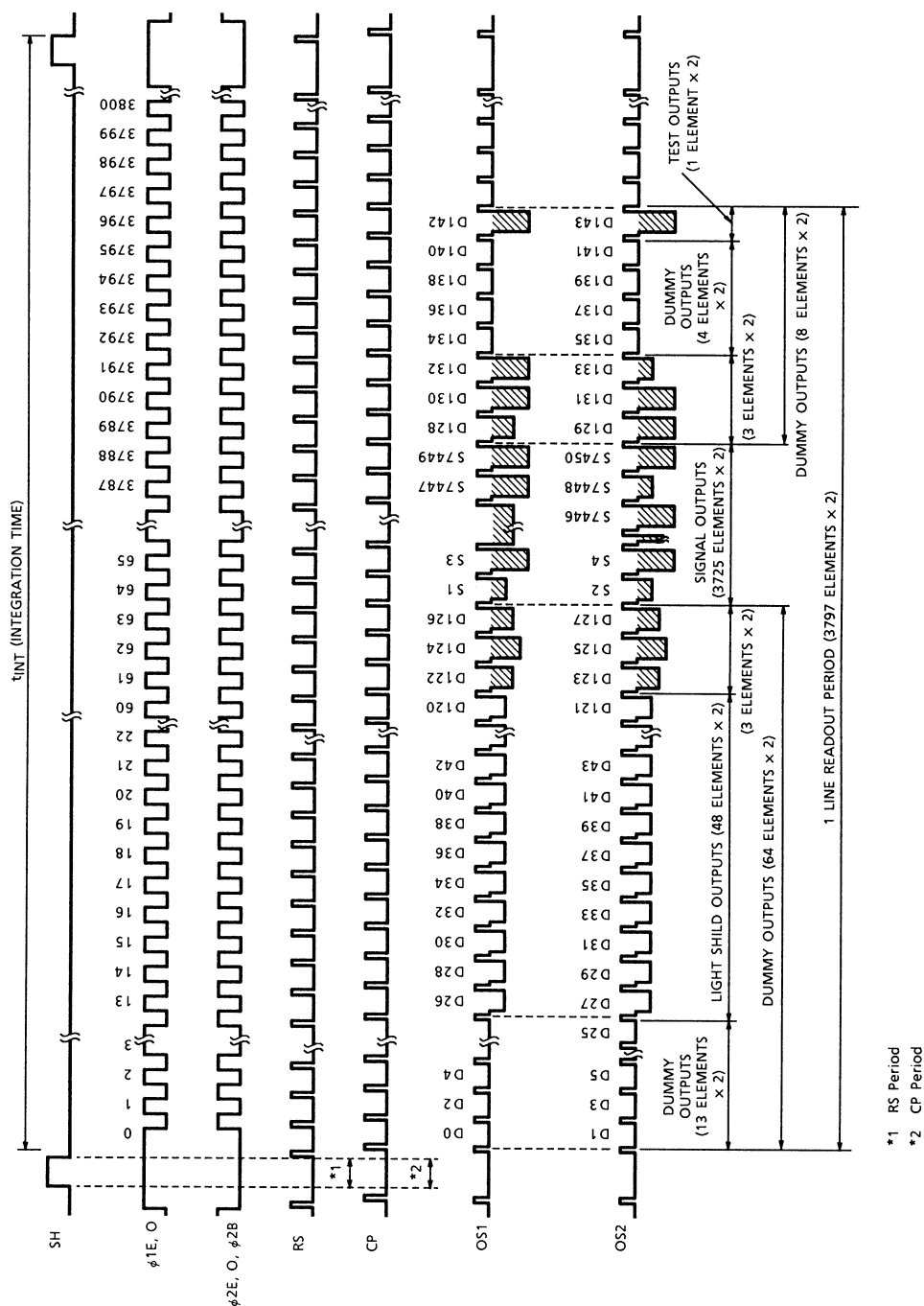
CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Voltage	"H" Level	$V_{\phi 1E, O}$ $V_{\phi 2E, O}$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Final Stage Clock Voltage	"H" Level	$V_{\phi 2B}$	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Shift Pulse Voltage	"H" Level	V_{SH}	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Reset Pulse Voltage	"H" Level	V_{RS}	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Clamp Pulse Voltage	"H" Level	V_{CP}	4.5	5	5.5	V
	"L" Level		0	—	0.5	
Power Supply Voltage		V_{OD}	11.4	12.0	13.0	V

CLOCK CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Frequency		f_{ϕ}	—	1	20	MHz
Reset Pulse Frequency		f_{RS}	—	1	20	MHz
Clock Capacitance (Note 10)		$C_{\phi E}$	—	250	—	pF
		$C_{\phi O}$	—	250	—	
Final Stage Clock Capacitance		$C_{\phi B}$	—	10	—	pF
Shift Gate Capacitance		C_{SH}	—	40	—	pF
Reset Gate Capacitance		C_{RS}	—	10	—	pF
Clamp Gate Capacitance		C_{CP}	—	10	—	pF

Note 10: $V_{OD} = 12\text{ V}$

TIMING CHART



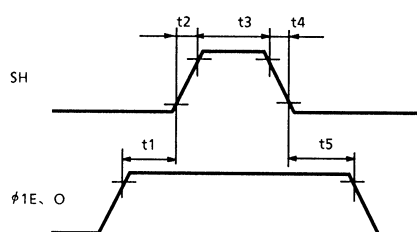
*1 RS Period

*2 CP Period

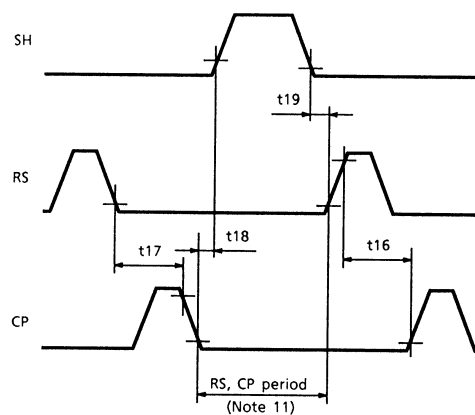
TCD1705D-7

TIMING REQUIREMENTS

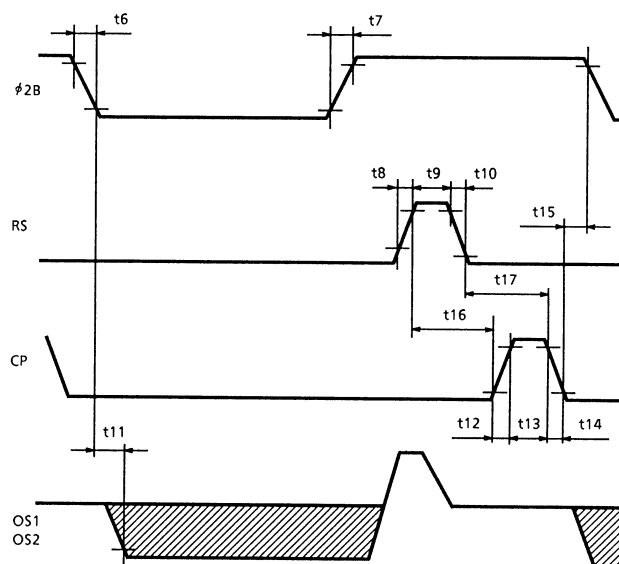
SH, $\phi 1$ Timing



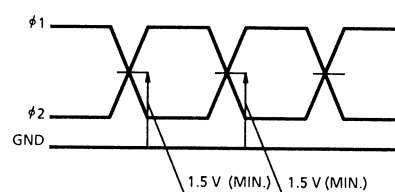
SH, RS, CP Timing



$\phi 2$, RS, CP, OS Timing



$\phi 1$, $\phi 2$ CROSS POINT



Note 11: Each RS and CP pins put to Low level during this period.

CHARACTERISTIC	SYMBOL	MIN.	TYP. (Note 12)	MAX.	UNIT
Pulse Timing of SH and $\phi 1E$, $\phi 1O$	t1, t5,	200	500	—	ns
SH Pulse Rise Time, Fall Time	t2, t4	0	50	—	ns
SH Pulse Width	t3	1000	1500	—	ns
$\phi 2B$ Pulse Rise Time, Fall Time	t6, t7	0	100	—	ns
RS Pulse Rise Time, Fall Time	t8, t10	0	20	—	ns
RS Pulse Width	t9	10	100	—	ns
Video Data Delay Time (Note 13)	t11	—	15	—	ns
CP Pulse Rise Time, Fall Time	t12, t14	0	20	—	ns
CP Pulse Width	t13	10	100	—	ns
Pulse Timing of $\phi 2B$ and CP	t15	0	50	—	ns
Pulse Timing of RS and CP	t16	0	100	—	ns
	t17	10	100	—	
Pulse Timing of SH and CP	t18	200	—	—	ns
Pulse Timing of SH and RS	t19	200	—	—	ns

Note 12: TYP. is the case of $f_{RS} = 1.0$ MHz

Note 13: TLoad Resistance is 100 k Ω

PRECAUTIONS FOR USE OF CCD IMAGE SENSOR**1. Static Electricity**

This device has some weakly terminals for static electricity. Therefore, please pay attention to treat this device.

CCD Image Sensor is protected against static electricity, but inferior puncture mode device due to static electricity is sometimes detected. In handling the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

- a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
- b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
- c. Ground the tools such as soldering iron, radio cutting plier or pincette.

It is not necessarily required to execute all precaution items for static electricity.

It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

2. Window Glass

As the dust and station on the glass window of the package will cause black flow on the picture, never fail to clean the glass surface before using. (Blow compressed vapor, and wipe off the dust, and dirt with soft cloth or paper slightly moistened with alcohol).

Fully take care for the handling of the device as the window glass will break or a strong friction is given to the window glass surface.

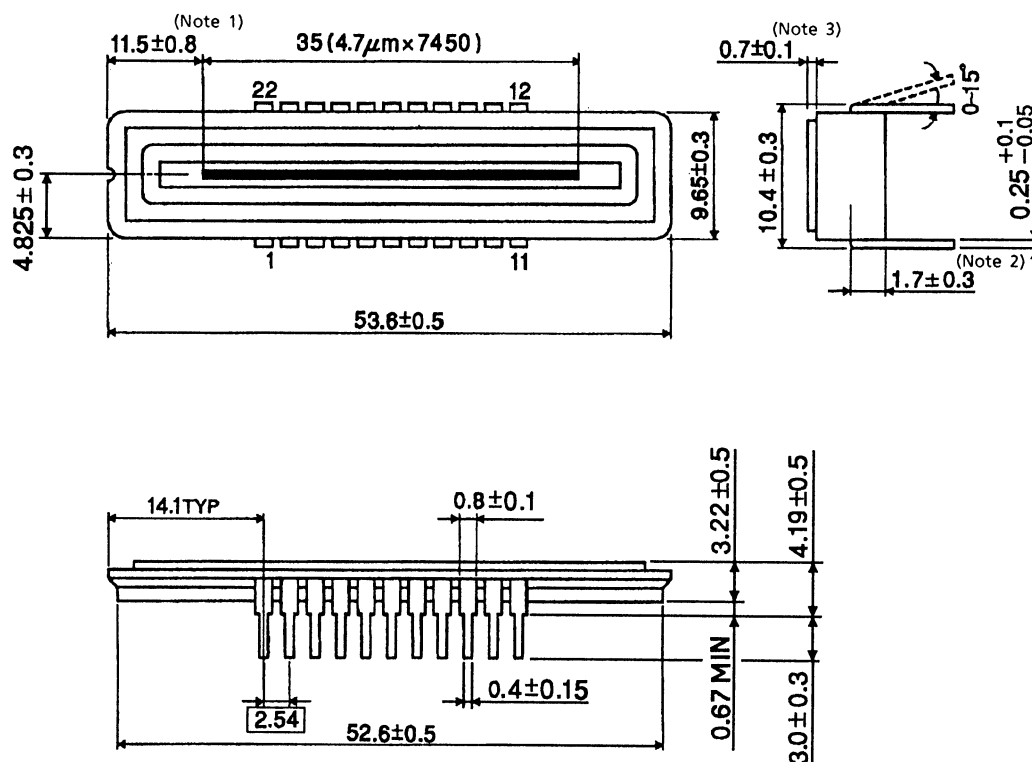
3. Incident Light

CCD image sensor has sensitivity in a wide range zone of light wave length, but its characteristics will sometimes widely change when used with long wave length input light outside the visual light zone.

PACKAGE DIMENSIONS

WDIP22-G-400-2.54D (C)

Unit : mm



Note 1: No.1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.

Note 2: TOP OF CHIP TO BOTTOM OF PACKAGE.

Note 3: GLASS THICKNESS (n=1.5)

Weight : 5.2g (Typ.)